

General Description

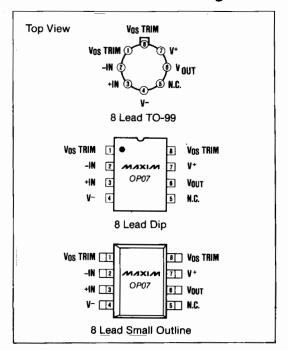
The OP07 is a precision operational amplifier with very low input offset voltage $(10\mu V \text{ typ.}, 25\mu V \text{ max.})$ for the OP07A), input offset drift of $0.2\mu V/^{\circ}C$ and low input bias current of 0.7nA. The wide input common mode range of $\pm 14V$ combined with high CMRR of 110dB minimum (OP07A), plus high input impedance and high open-loop gain make these devices particularly useful for high-gain instrumentation applications.

The excellent linearity and gain accuracy are maintained at high open-loop gains, over both time and temperature. The OP07 has become an industry standard and Maxim's reliability and quality are added advantages.

Applications

Precision Amplifiers Thermocouple Amplifiers Low Level Signal Processing Medical Instrumentation Strain Gauge Amplifiers High Accuracy Data Acquisition

Pin Configuration



Features

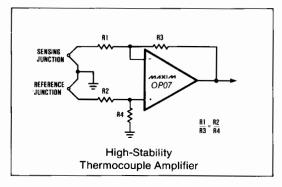
- Ultra Low Offset Voltage: 10µV
- Ultra Low Offset Voltage Drift: 0.2µV/°C
- Ultra Stable vs. Time: 0.2 µV/Month
- Ultra Low Noise: 0.35µV_{p-p}
- Wide Supply Voltage: ±3V to ±18V
- High Common Mode Input: ±14V
- **No External Components Required**
- ♦ Fits AD510, 725, 108A/308A, 741 Sockets

Ordering Information

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PART	TEMP. RANGE	PACKAGE
OP07AJ	-55°C to +125°C	TO-99
OP07J	-55°C to +125°C	TO-99
OP07EJ	0°C to +70°C	TO-99
OP07CJ	0°C to +70°C	TO-99
OP07DJ	0°C to +70°C	TO-99
OP07EP	0°C to +70°C	8 Lead Plastic Dip
OP07CP	0°C to +70°C	8 Lead Plastic Dip
OP07DP	0°C to +70°C	8 Lead Plastic Dip
OP07AZ	-55°C to +125°C	8 Lead Hermetic Dip
OP07Z	-55°C to +125°C	8 Lead Hermetic Dip
OP07EZ	0°C to +70°C	8 Lead Hermetic Dip
OP07CZ	0°C to +70°C	8 Lead Hermetic Dip
OP07ECSA	0°C to +70°C	8 Lead Small Outline
OP07CCSA	0°C to +70°C	8 Lead Small Outline
OP07DCSA	0°C to +70°C	8 Lead Small Outline
OP07D/D	0°C to +70°C	Dice

^{*} Contact factory for dice specifications.

Typical Operating Circuit



ABSOLUTE MAXIMUM RATINGS

Total Supply Voltage (V ⁺ to V ⁻) ±22V	Storage Temperature Range65°C to +150°C
Internal Power Dissipation 500mW	Operating Temperature Range
TO-99(J) — derate at 7.1mW/°C above +80°C	OP07AJ, OP07AZ, OP07J and OP07Z55°C to +125°C
Hermetic Dip(Z) — derate at 6.7mW/°C above +75°C	All Other Parts 0°C to +70°C
Plastic Dip(P) — derate at 5.6mW/°C above +36°C	Lead Temperature (Soldering, 10 sec) +300°C
Small Outline — derate at 5mW/°C above +55°C	Duration of Output Short Circuit Indefinite
Differential Input Voltage ±30V	Junction Temperature (T _i)65°C to +160°C
Input Voltage (Note 1) ±22V	

Note 1: For supply voltages less than ±22V, the absolute maximum input voltage is equal to the supply voltage.

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_S = \pm 15V, T_A = +25^{\circ}C, unless otherwise noted.)$

0404145550	SYMBOL	CONDITIONS		OP07A			UNITS		
PARAMETER			MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Input Offset Voltage	Vos	(Note 2)		10 '	25		30	75	μV
Long Term Input Offset Voltage Stability	V _{OS} /Time	(Note 3)		0.2	1.0		0.2	1.0	μV/ Month
Input Offset Current	los			0.3	2.0		0.4	2.8	nA
Input Bias Current	I _B			±0.7	±2.0		±1.0	±3.0	nA
Input Noise Voltage	e _{NP-P}	0.1Hz to 10Hz (Note 4)		0.35	0.6	·	0.35	0.6	μV _{P-P}
Input Noise Voltage Density	e _N	f _O = 10Hz (Note 4) f _O = 100Hz (Note 4) f _O = 1000Hz (Note 4)		10.3 10.0 9.6	18.0 13.0 11.0		10.3 10.0 9.6	18.0 13.0 11.0	nV/√Hz
Input Noise Current	I _{N P-P}	0.1Hz to 10Hz (Note 4)		14	30		14	30	pA _{P-P}
Input Noise Current Density	IN	f _O = 10Hz (Note 4) f _O = 100Hz (Note 4) f _O = 1000Hz (Note 4)		0.32 0.14 0.12	0.80 0.23 0.17		0.32 0.14 0.12	0.80 0.23 . 0.17	p A ∕√H:
Input Resistance Differential-Mode	R _{IN}	(Note 5)	30	80		20	60		МΩ
Input Resistance Common-Mode	R _{INCM}			200			200		GΩ
Input Voltage Range	IVR		±13	±14		±13	±14		V
Common-Mode Rejection Ratio	CMRR	V _{CM} = ±13V	110	126		110	126		dB
Power Supply Rejection Ratio	PSRR	V _S = ±3V to ±18V		4	10		4	10	μV/V
Large Signal Voltage Gain	A _{vo}	$R_L \ge 2k\Omega$, $V_O = \pm 10V$ $R_L \ge 500\Omega$, $V_O = \pm 0.5V$ $V_S = \pm 3V$ (Note 5)	300 150	500 400		200 150	500 400		V/mV
Output Voltage Swing	٠٧o	$\begin{aligned} R_L &\geq 10k\Omega \\ R_L &\geq 2k\Omega \\ R_1 &\geq 1k\Omega \end{aligned}$	±12.5 ±12.0 ±10.5	±13.0 ±12.8 ±12.0	_	±12.5 ±12.0 ±10.5	±13.0 ±12.8 ±12.0	·	v

- Note 2: OP07A grade V_{OS} is measured one minute after application of power. For all other grades V_{OS} is measured approximately 0.5 seconds after application of power.
- Note 3: Long-Term Input Offset Voltage Stability refers to the average trend line of V_{OS} vs. Time over extended periods after the first 30 days of operation. Excluding the initial hour of operation, changes in V_{OS} during the first 30 operating days are typically 2.5 µV. Parameter is sample tested.
- Note 4: Sample tested.
- Note 5: Guaranteed by design.

ELECTRICAL CHARACTERISTICS (continued) $(V_S = \pm 15V, T_A = +25^{\circ}C, unless otherwise noted.)$

PARAMETER		CONDITIONS		OP07A			UNITS		
	SYMBOL		MIN	TYP	MAX	MIN	TYP	MAX	ONIIS
Slew Rate	SR	$R_L \ge 2k\Omega$ (Note 6)	0.1	0.3		0.1	0.3		V/μS
Closed-Loop Bandwidth	BW	A _{VCL} = +1V (Note 6)	0.4	0.6		0.4	0.6		MHz
Open-Loop Output Resistance	Ro	V _O = 0V, I _O = 0		60			60		Ω
Power Consumption	P _D	$V_S = \pm 15V$, No Load $V_S = \pm 3V$, No Load		75 4	120 6		75 4	120 6	mW
Offset Adjustment Range		R _P = 20kΩ		±4			±4		mV

Note 6: Sample tested.

ELECTRICAL CHARACTERISTICS (V_S = \pm 15V, -55°C \leq T_A \leq +125°C, unless otherwise noted.)

		CONDITIONS		OP07A			UNITS		
PARAMETER	SYMBOL		MIN	TYP	MAX	MIN	TYP	MAX	ONITS
Input Offset Voltage	Vos	(Note 7)		25	60		60	200	μV
Average Temperature Coefficient of Input Offset Voltage	TCVos	(Note 8)		0.2	0.6		0.3	1.3	μV/°C
Input Offset Current	Ios			0.8	4.0		1.2	5.6	nA
Average Input Offset Current Drift	TCIOS	(Note 8)		5	25		8	50	pA/°C
Input Bias Current	I _B			±1.0	±4.0		±2.0	±6.0	nA
Average Input Bias Current Drift	TCIB	(Note 8)		8	25		13	50	pA/°C
Input Voltage Range	IVR		±13	±13.5		±13	±13.5		V
Common-Mode Rejection Ratio	CMRR	V _{CM} = ±13V	106	123		106	123		dB
Power Supply Rejection Ratio	PSRR	V _S = ±3V to ±18V		5	20		5	20	μV/V
Large Signal Voltage Gain	A _{vo}	$R_L \ge 2k\Omega$, $V_O = \pm 10V$	200	400		150	400		V/mV
Output Voltage Swing	V _o	$R_L \ge 2k\Omega$	±12.0	±12.6		±12.0	±12.6		V

Note 7: OP07A grade Offset Voltage is measured one minute after application of power. For all other grades Vos is measured 0.5 seconds after power on.

Note 8: Sample tested.

ELECTRICAL CHARACTERISTICS

($V_S = \pm 15V$, $T_A = +25$ °C, unless otherwise noted.)

DADAMETER	OVMDC:	CONDITIONS	OP07E				OP07C	;	OP07D			
PARAMETER	SYMBOL		MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	1
Input Offset Voltage	Vos	(Note 1)		30	75		60	150		60	150	μV
Long Term Input Offset Voltage Stability	V _{OS} /Time	(Note 2)		0.3	1.5		0.4	2.0		0.5	3.0	μV/ Month
Input Offset Current	los			0.5	3.8		0.8	6.0		8.0	6.0	nA
Input Bias Current	I _B			±1.2	±4.0		±1.8	±7.0		±2.0	±12.0	nA
Input Noise Voltage	e _{N P-P}	0.1Hz to 10Hz (Note 3)		0.35	0.6		0.38	0.65		0.38	0.65	μV _{P-P}
Input Noise Voltage Density	e _N	f _O = 10Hz (Note 3) f _O = 100Hz (Note 3) f _O = 1000Hz (Note 3)		10.3 10.0 9.6	18.0 13.0 11.0		10.5 10.2 9.8	20.0 13.5 11.5		10.5 10.3 9.8	20.0 13.5 11.5	nV/√Hz
Input Noise Current	I _{N P-P}	0.1Hz to 10Hz (Note 3)		14	30		15	35		15	35	pA _{P-P}
Input Noise Current Density	IN	f _O = 10Hz (Note 3) f _O = 100Hz (Note 3) f _O = 1000Hz (Note 3)		0.32 0.14 0.12	0.80 0.23 0.17		0.35 0.15 0.13	0.90 0.27 0.18		0.35 0.15 0.13	0.90 0.27 0.18	pA∕√Hz
Input Resistance Differential-Mode	R _{IN}	(Note 4)	15	50		8	33		7	31		МΩ
Input Resistance Common-Mode	R _{INCM}			160			120			120		GΩ
Input Voltage Range	IVR		±13	±14		±13	±14		±13	±14		V
Common-Mode Rejection Ratio	CMRR	V _{CM} = ±13V	106	123		100	120		94	110		dB
Power Supply Rejection Ratio	PSRR	V _S = ±3V to ±18V		5	20		7	32		7	32	μV/V
Large Signal Voltage Gain	A _{vo}	$R_L \ge 2k\Omega$, $V_O = \pm 10V$ $R_L \ge 500\Omega$, $V_O = \pm 0.5V$ $V_S = \pm 3V$ (Note 5)	200 150	500 400		120 100	400 400		120	400 400		V/mV
Output Voltage Swing	v _o	$\begin{aligned} R_L &\geq 10k\Omega \\ R_L &\geq 2k\Omega \\ R_L &\geq 1k\Omega \end{aligned}$	±12.0	±13.0 ±12.8 ±12.0		±12.0 ±11.5	±13.0 ±12.8 ±12.0		±12.0 ±11.5	±13.0 ±12.8 ±12.0		V
Slew Rate	SR	$R_L \ge 2k\Omega$ (Note 3)	0.1	0.3		0.1	0.3		0.1	0.3		V/µS
Closed-Loop Bandwidth	BW	A _{VCL} = +1V (Note 3)	0.4	0.6		0.4	0.6		0.4	0.6		MHz
Open-Loop Output Resistance	Ro	V _O = 0V, I _O = 0		60			60			60		Ω
Power Consumption	Pd	$V_S = \pm 15V$, No Load $V_S = \pm 3V$, No Load		75 4	120 6		80 4	150 8		80 4	150 8	mW
Offset Adjustment Range		R _P = 20kΩ		±4			±4			±4		mV

Note 1: Input Offset Voltage measurements are performed by automated test equipment approximately 0.5 seconds after application of

Note 2.

Note 2.

Note 3.

Note 4.

Note 4.

Note 4.

Note 4.

Note 5.

Note 6.

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Note 6.

Note 6.

Note 7.

Note 7.

Note 8.

Note 8.

Note 9.

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ELECTRICAL CHARACTERISTICS

(V_S = ± 15 V, 0°C \leq T_A \leq +70°C, unless otherwise noted.)

PARAMETER	everou conditions		OP07E			OP07C			OP07D			
	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	1
Input Offset Voltage	Vos	(Note 5)		45	130		85	250		85	250	μV
Average Temperature Coefficient of Input Offset Voltage	TCVos	(Note 6)		0.3	1.3		0.4	1.8		0.7	2.5	μV/°C
Input Offset Current	Ios			0.9	5.3		1.6	8.0		1.6	8.0	nA
Average Input Offset Current Drift	TCIOS	(Note 6)		8	35		12	50		12	50	pA/°C
Input Bias Current	I _B			±1.5	±5.5		±2.2	±9.0		±3.0	±14	nA
Average Input Bias Current Drift	TCIB	(Note 6)		13	35		18	50		18	50	pA/°C
Input Voltage Range	IVR		±13.0	±13.5		±13.0	±13.5		±13.0	±13.5		٧
Common-Mode Rejection Ratio	CMRR	V _{CM} = ±13V	103	123		97	120		94	106		dB
Power Supply Rejection Ratio	PSRR	V _S = ±3V to ±18V		7	32		10	51		10	51	μV/V
Large Signal Voltage Gain	A _{vo}	$R_L \ge 2k\Omega$, $V_O = \pm 10V$	180	400		100	400		100	400		V/mV
Output Voltage Swing	V _o	$R_L \ge 2k\Omega$	±12.0	±12.6		±11.0	±12.6		±11.0	±12.6		V

Input Offset Voltage is measured 0.5 seconds after application of power. Sample tested.

Note 5: Note 6:

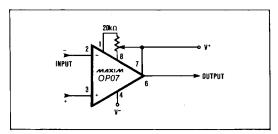


Figure 1. Optional Offset Nulling Circuit.

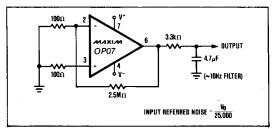
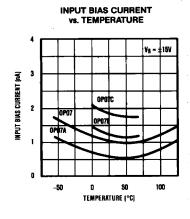
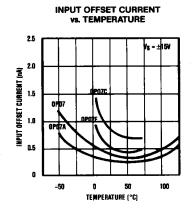
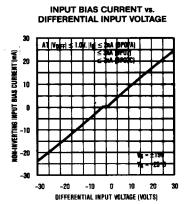
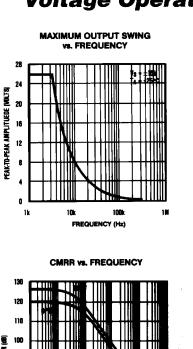


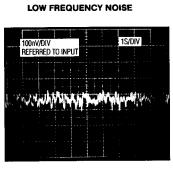
Figure 2. Low Frequency Noise Test Circuit.

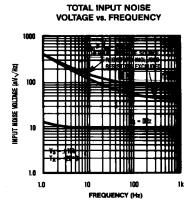


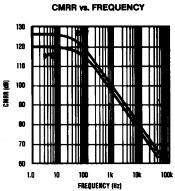


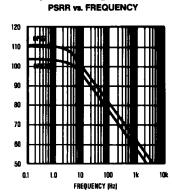


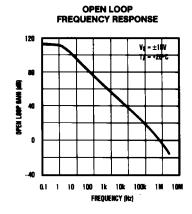


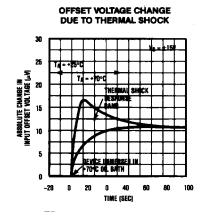


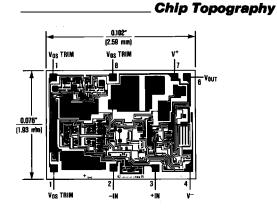




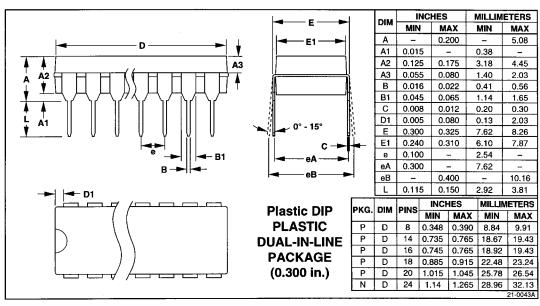


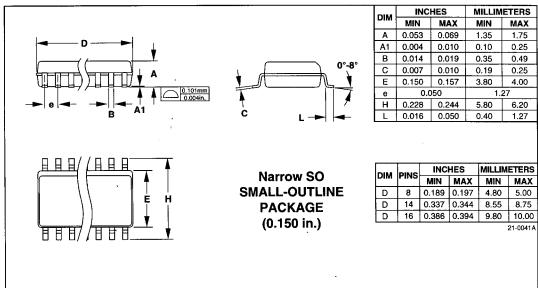




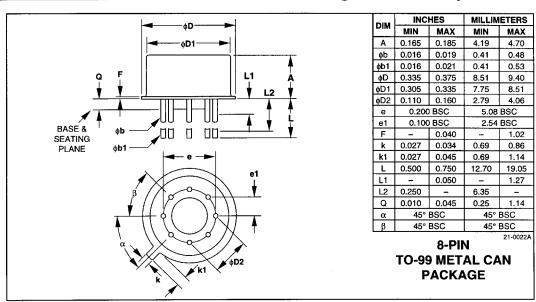


Package Information





Package Information (continued)



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